

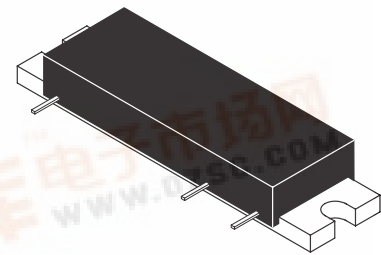
The RF Line Cellular Band RF Linear LDMOS Amplifier

Designed for ultra-linear amplifier applications in 50 ohm systems operating in the cellular frequency band. A silicon FET Class A design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for the most demanding analog or digital modulation systems, such as TDMA and CDMA.

- Third Order Intercept: 49 dBm Typ
- Power Gain: 17.5 dB Typ (@ f = 880 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- Ideal for Feedforward Base Station Applications
- For Use in TDMA and CDMA Multi-Carrier Applications

MHL9318

**3.0 W, 17.5 dB
 860–900 MHz
 RF LINEAR LDMOS AMPLIFIER**



CASE 301AS-01, STYLE 1

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{DD}	30	Vdc
RF Input Power	P _{in}	+20	dBm
Storage Temperature Range	T _{stg}	-40 to +100	°C
Operating Case Temperature Range	T _C	-20 to +100	°C

ELECTRICAL CHARACTERISTICS (V_{DD} = 28 Vdc, T_C = 25°C; 50 Ω System)

Characteristic	Symbol	Min	Typ	Max	Unit
Supply Current	I _{DD}	—	500	560	mA
Power Gain (f = 880 MHz)	G _p	17	17.5	18.5	dB
Gain Flatness (f = 860–900 MHz)	G _F	—	0.1	0.2	dB
Power Output @ 1 dB Comp. (f = 880 MHz)	P _{out} 1 dB	—	35.5	—	dBm
Input VSWR (f = 860–900 MHz)	VSWR _{in}	—	1.2:1	1.5:1	
Output VSWR (f = 860–900 MHz)	VSWR _{out}	—	1.2:1	1.5:1	
Third Order Intercept (f ₁ = 879 MHz, f ₂ = 884 MHz)	ITO	47	49	—	dBm
Noise Figure (f = 960 MHz)	NF	—	3	4.5	dB

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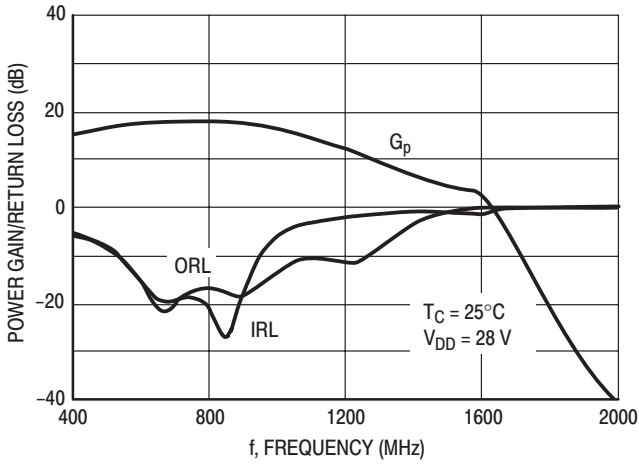


Figure 1. Power Gain, Input Return Loss, Output Return Loss versus Frequency

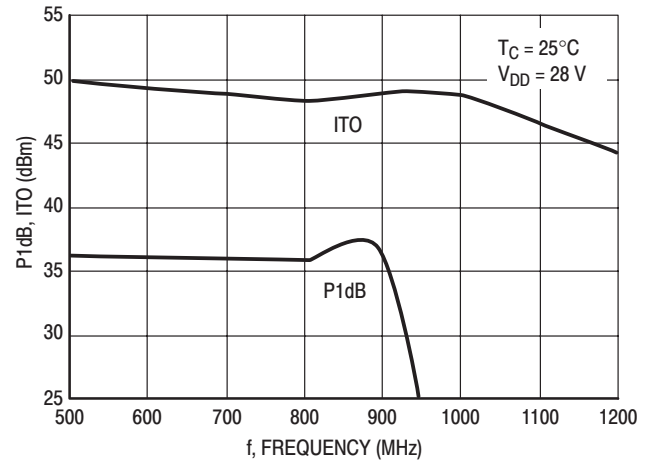


Figure 2. P1dB, ITO versus Frequency

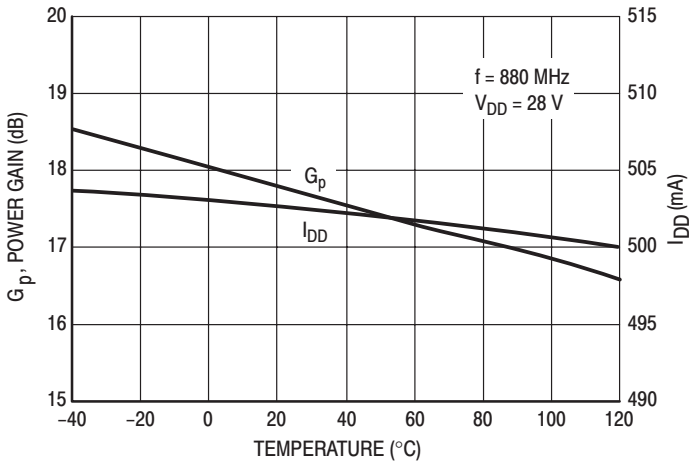


Figure 3. Power Gain, I_{DD} versus Temperature

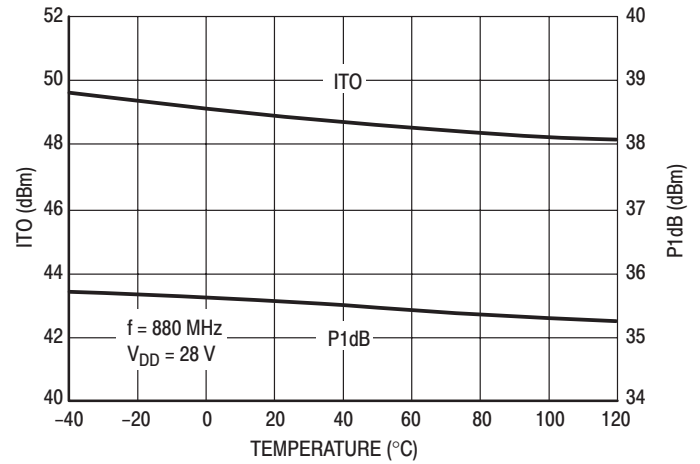


Figure 4. ITO, P1dB versus Temperature

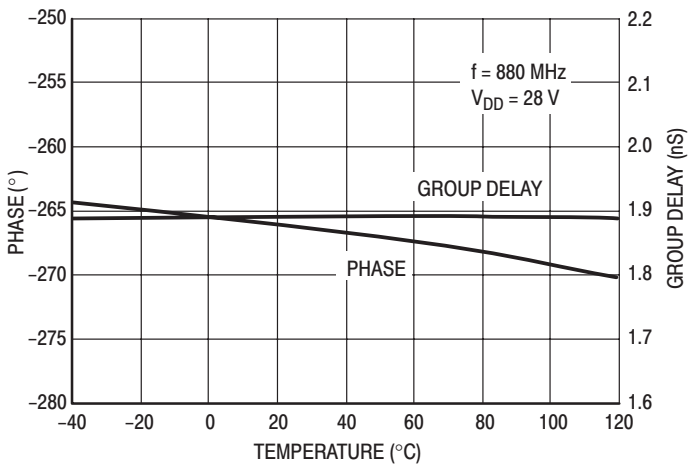


Figure 5. Phase⁽¹⁾, Group Delay⁽¹⁾ versus Temperature
⁽¹⁾In Production Test Fixture

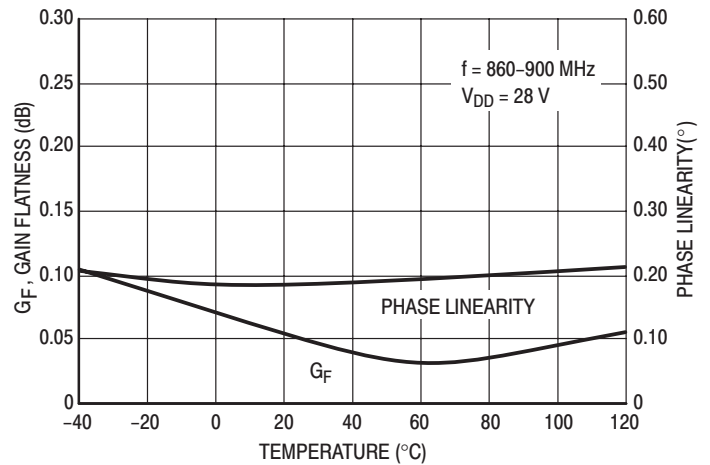


Figure 6. Gain Flatness, Phase Linearity versus Temperature

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TYPICAL CHARACTERISTICS

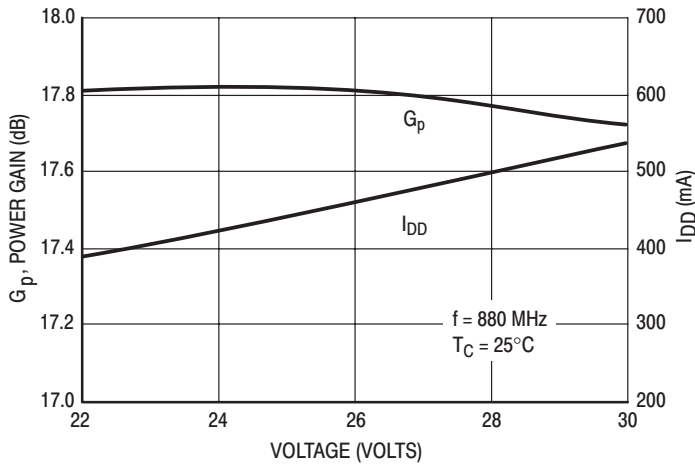


Figure 7. Power Gain, I_{DD} versus Voltage

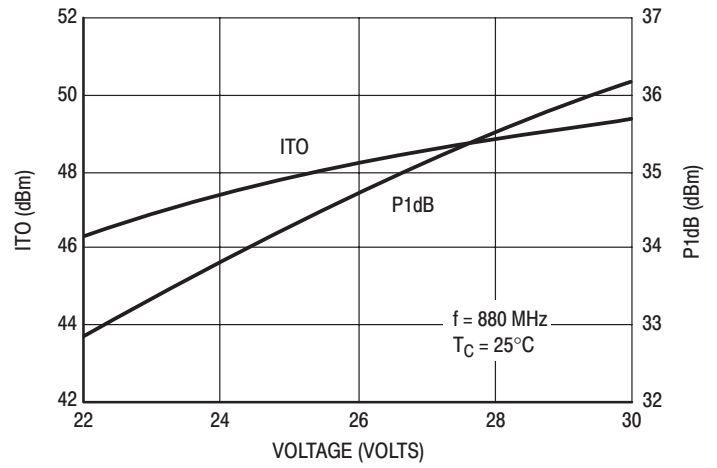


Figure 8. ITO, P1dB versus Voltage

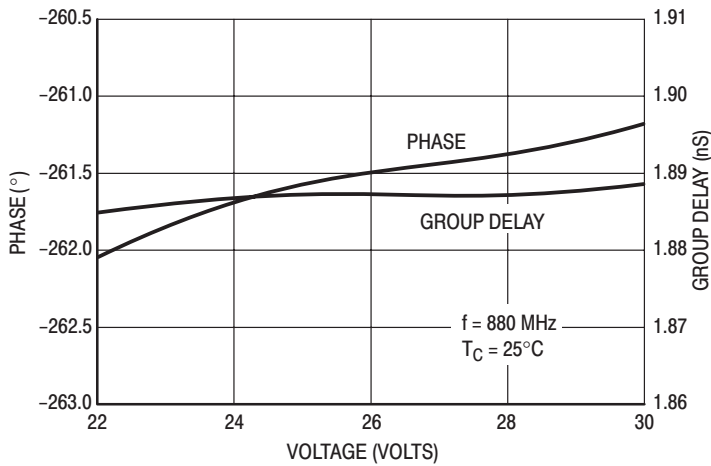


Figure 9. Phase⁽¹⁾, Group Delay⁽¹⁾ versus Voltage
⁽¹⁾In Production Test Fixture

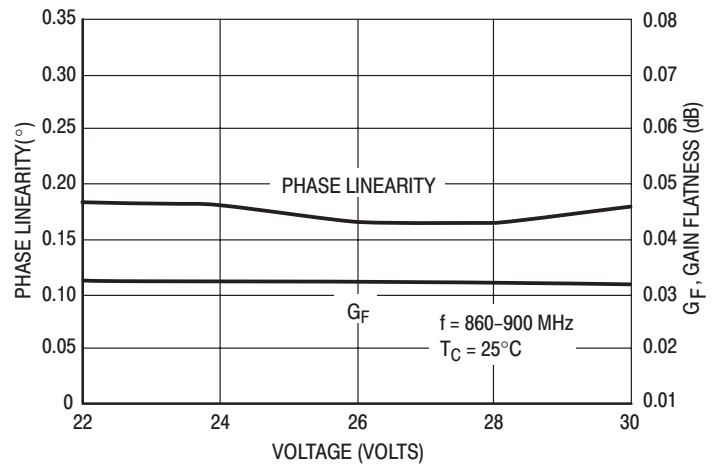
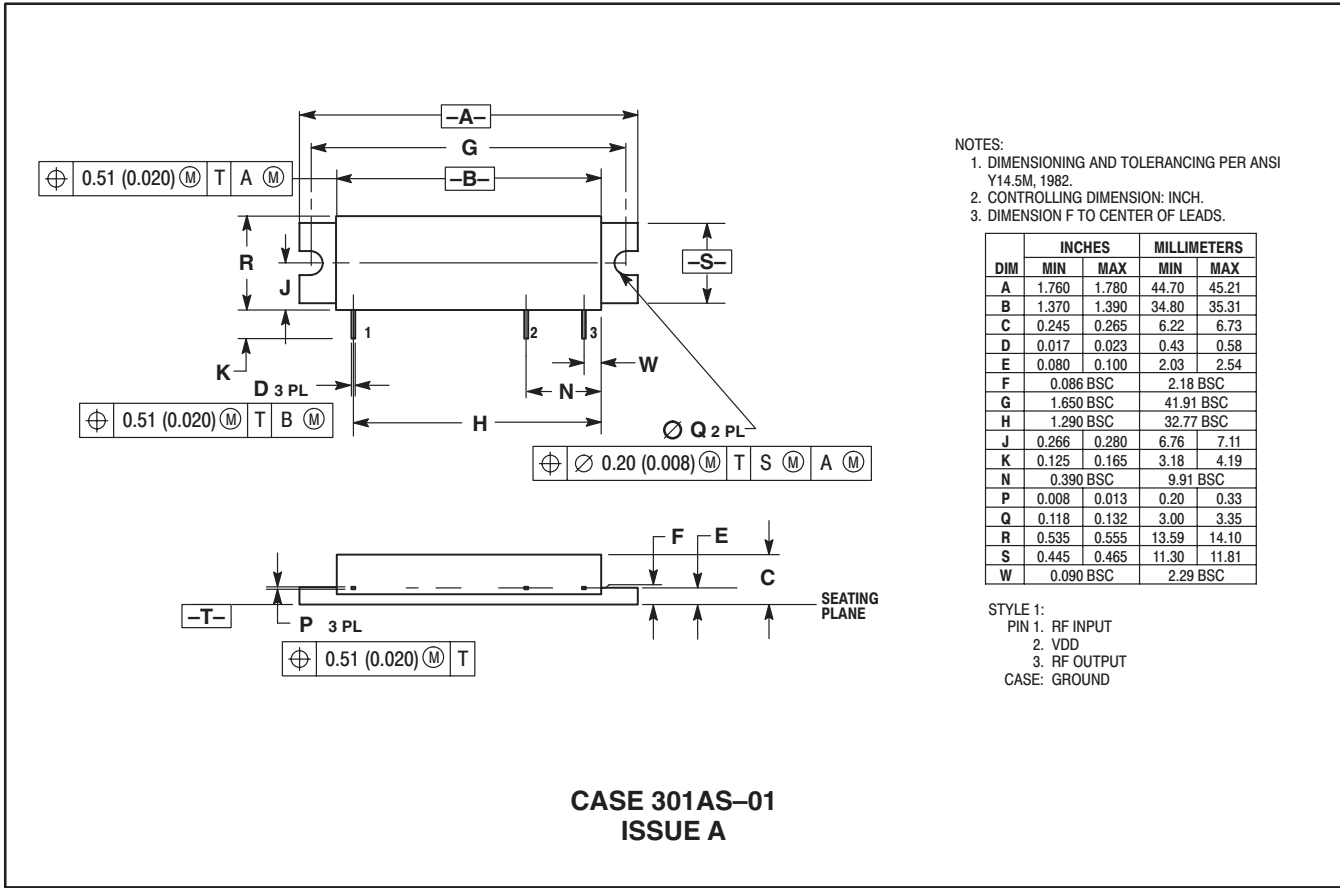


Figure 10. Phase Linearity, Gain Flatness versus Voltage

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PACKAGE DIMENSIONS



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